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REVISION HISTORY**9/2017—Rev. F to Rev. G**

Changed ADA409x to ADA4096-2	Throughout
Changed CP-16-27 to CP-16-22	Throughout
Changes to Figure 12 and Figure 13	10
Changes to Figure 26	13
Changes to Figure 39	16
Updated Outline Dimensions	22
Changes to Ordering Guide	24

12/2014—Rev. E to Rev. F

Changes to EPAD Note, Figure 2	1
Changes to EPAD Note, Figure 5 and Table 7	7
Changes to EPAD Note, Figure 7 and Table 8	8

3/2014—Rev. D to Rev. E

Changes to Figure 10 and Figure 12	9
Changes to Figure 23 and Figure 25	12
Changes to Figure 36 and Figure 38	15

5/2013—Rev. C to Rev. D

Changes to Pin Connection Diagrams Section	1
Changes to Pin Configurations and Function Descriptions Section	7
Added Figure 10, Renumbered Sequentially	9
Added Figure 23	12
Added Figure 36	15

8/2012—Rev. B to Rev. C

Changes to Table 8	8
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8/2012—Rev. A to Rev. B

Added ADA4096-4	Universal
Changes to Features Section	1
Added Figure 3	1
Changes to Pin Connection Diagrams Section	1
Changes to Input Bias Current, Common-Mode Rejection Ratio, Large Signal Voltage Gain, and Supply Current per Amplifier Parameters, and –3 dB Closed-Loop Bandwidth Symbol, Table 2	3
Changes to Input Bias Current, Common-Mode Rejection Ratio, Large Signal Voltage Gain, and Parameters, and –3 dB Closed-Loop Bandwidth Symbol, Table 3	4
Changes to Input Bias Current, Common-Mode Rejection Ratio, Large Signal Voltage Gain, Output Voltage High, and Output Voltage Low Parameters, and –3 dB Closed-Loop Bandwidth Symbol, Table 4	5
Changes to Table 6	7
Added Pin Configurations and Function Descriptions Section	8
Added Figure 4 and Figure 5, Renumbered Sequentially	8
Added Table 7, Renumbered Sequentially	8
Added Figure 6, Figure 7, and Table 8	9
Updated Outline Dimensions	18
Changes to Ordering Guide	20

3/2012—Rev. 0 to Rev. A

Changed –3 dB Closed-Loop Bandwidth from 97 kHz to 970 kHz, Table 2	3
Changed –3 dB Closed-Loop Bandwidth from 114 kHz to 1140 kHz, Table 3	4
Changed to –3 dB Closed-Loop Bandwidth from 152 kHz to 1520 kHz, Table 4	5
Updated Outline Dimensions	18

7/2011—Revision 0: Initial Version

SPECIFICATIONS

ELECTRICAL SPECIFICATIONS, $V_{SY} = \pm 1.5\text{ V}$

$V_{SY} = \pm 1.5\text{ V}$, $V_{CM} = V_{SY}/2$, $T_A = 25^\circ\text{C}$, unless otherwise noted.

Table 2.

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	$0^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		35	300	μV
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			450	μV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		1	900	$\mu\text{V}/^\circ\text{C}$
Input Bias Current	I_B	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		± 10	± 25	nA
					± 30	nA
Input Offset Current	I_{OS}	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		± 0.1	± 1.5	nA
					± 3	nA
Input Voltage Range			-1.5		+1.5	V
Common-Mode Rejection Ratio	CMRR	$V_{CM} = 0\text{ V to } \pm 1.5\text{ V}$	61	77		dB
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	58			dB
Large Signal Voltage Gain	A_{VO}	$R_L = 10\text{ k}\Omega$, $V_O = -1.4\text{ V to } +1.4\text{ V}$	91	94		dB
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	84			dB
		$R_L = 2\text{ k}\Omega$, $V_O = -1.3\text{ V to } +1.3\text{ V}$	86	92		dB
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	77			dB
MATCHING CHARACTERISTICS						
Offset Voltage		$T_A = 25^\circ\text{C}$		100	300	μV
OUTPUT CHARACTERISTICS						
Output Voltage High	V_{OH}	$R_L = 10\text{ k}\Omega$ to GND	1.48	1.49		V
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	1.45			V
		$R_L = 2\text{ k}\Omega$ to GND	1.45	1.46		V
		$-40^\circ\text{C to } +125^\circ\text{C}$	1.40			V
Output Voltage Low	V_{OL}	$R_L = 10\text{ k}\Omega$ to GND		-1.49	-1.48	V
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			-1.45	V
		$R_L = 2\text{ k}\Omega$ to GND		-1.48	-1.47	V
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			-1.40	V
Short-Circuit Limit	I_{SC}	Source/sink		± 10		mA
Closed-Loop Impedance	Z_{OUT}	$f = 100\text{ kHz}$, $A_V = 1$		102		Ω
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_{SY} = 3\text{ V to } 36\text{ V}$	100			dB
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	90			dB
Supply Current per Amplifier	I_{SY}	$V_O = V_{SY}/2$		40	50	μA
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			80	μA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 100\text{ k}\Omega$, $C_L = 30\text{ pF}$		0.25		V/ μs
Gain Bandwidth Product	GBP	$V_{IN} = 5\text{ mV p-p}$, $R_L = 10\text{ k}\Omega$, $A_V = 100$		501		kHz
Unity-Gain Crossover	UGC	$V_{IN} = 5\text{ mV p-p}$, $R_L = 10\text{ k}\Omega$, $A_V = 1$		465		kHz
Phase Margin	Φ_M			51		Degrees
-3 dB Closed-Loop Bandwidth	$f_{-3\text{ dB}}$	$A_V = 1$, $V_{IN} = 5\text{ mV p-p}$		970		kHz
NOISE PERFORMANCE						
Voltage Noise	$e_n\text{ p-p}$	0.1 Hz to 10 Hz		0.7		$\mu\text{V p-p}$
Voltage Noise Density	e_n	$f = 1\text{ kHz}$		27		nV/ $\sqrt{\text{Hz}}$
Current Noise Density	i_n	$f = 1\text{ kHz}$		0.2		pA/ $\sqrt{\text{Hz}}$

ELECTRICAL SPECIFICATIONS, $V_{SY} = \pm 5\text{ V}$ $V_{SY} = \pm 5\text{ V}$, $V_{CM} = V_{SY}/2$, $T_A = 25^\circ\text{C}$, unless otherwise noted.**Table 3.**

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		35	300	μV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$			1	500	$\mu\text{V}/^\circ\text{C}$
Input Bias Current	I_B	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		± 10	± 25	nA
Input Offset Current	I_{OS}	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		± 1.5	± 2	nA
Input Voltage Range		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			± 3	nA
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -5\text{ V to } +5\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	-5		+5	V
		$V_{CM} = -3\text{ V to } +3\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	72	86		dB
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	68			dB
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	91	103		dB
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	85			dB
Large Signal Voltage Gain	A_{VO}	$R_L = 10\text{ k}\Omega$, $V_O = \pm 4.8\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	102	111		dB
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	99			dB
		$R_L = 2\text{ k}\Omega$, $V_O = \pm 4.7\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	93	103		dB
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	88			dB
MATCHING CHARACTERISTICS						
Offset Voltage		$T_A = 25^\circ\text{C}$		100	300	μV
OUTPUT CHARACTERISTICS						
Output Voltage High	V_{OH}	$R_L = 10\text{ k}\Omega$ to GND $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	4.96	4.97		V
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	4.95			V
		$R_L = 2\text{ k}\Omega$ to GND $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	4.80	4.90		V
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	4.70			V
Output Voltage Low	V_{OL}	$R_L = 10\text{ k}\Omega$ to GND $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		-4.98	-4.97	V
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			-4.95	V
		$R_L = 2\text{ k}\Omega$ to GND $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		-4.90	-4.80	V
		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			-4.75	V
Short-Circuit Limit	I_{SC}	Source/sink		± 10		mA
Closed-Loop Impedance	Z_{OUT}	$f = 100\text{ kHz}$, $A_V = 1$		71		Ω
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_{SY} = 3\text{ V to } 36\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	100			dB
			90			dB
Supply Current per Amplifier	I_{SY}	$V_O = V_{SY}/2$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		47	55	μA
					75	μA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 100\text{ k}\Omega$, $C_L = 30\text{ pF}$		0.3		$\text{V}/\mu\text{s}$
Gain Bandwidth Product	GBP	$V_{IN} = 5\text{ mV p-p}$, $R_L = 10\text{ k}\Omega$, $A_V = 100$		595		kHz
Unity-Gain Crossover	UGC	$V_{IN} = 5\text{ mV p-p}$, $R_L = 10\text{ k}\Omega$, $A_V = 1$		550		kHz
Phase Margin	Φ_M			52		Degrees
-3 dB Closed-Loop Bandwidth	$f_{-3\text{ dB}}$	$A_V = 1$, $V_{IN} = 5\text{ mV p-p}$		1140		kHz
NOISE PERFORMANCE						
Voltage Noise	e_n p-p	0.1 Hz to 10 Hz		0.7		$\mu\text{V p-p}$
Voltage Noise Density	e_n	$f = 1\text{ kHz}$		27		$\text{nV}/\sqrt{\text{Hz}}$
Current Noise Density	i_n	$f = 1\text{ kHz}$		0.2		$\text{pA}/\sqrt{\text{Hz}}$

ELECTRICAL SPECIFICATIONS, $V_{SY} = \pm 15\text{ V}$ $V_{SY} = \pm 15\text{ V}$, $V_{CM} = V_{SY}/2$, $V_O = 0.0\text{ V}$, $T_A = 25^\circ\text{C}$, unless otherwise noted.**Table 4.**

Parameter	Symbol	Test Conditions/Comments	Min	Typ	Max	Unit
INPUT CHARACTERISTICS						
Offset Voltage	V_{OS}	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		35	300	μV
Offset Voltage Drift	$\Delta V_{OS}/\Delta T$			1	500	$\mu\text{V}/^\circ\text{C}$
Input Bias Current	I_B	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		± 3	± 25	nA
Input Offset Current	I_{OS}	$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		± 0.1	± 1.5	nA
Input Voltage Range		$-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			± 3	nA
Common-Mode Rejection Ratio	CMRR	$V_{CM} = -15\text{ V to } +15\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	-15		+15	V
		$V_{CM} = -13\text{ V to } +13\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	81	95		dB
			75			dB
			95	107		dB
			89			dB
Large Signal Voltage Gain	A_{VO}	$R_L = 10\text{ k}\Omega$, $V_O = \pm 14.7\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	109	120		dB
		$R_L = 2\text{ k}\Omega$, $V_O = \pm 11\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	105			dB
			99	112		dB
			90			dB
Input Capacitance						
Differential Mode	C_{DM}			2.5		pF
Common Mode	C_{CM}			7		pF
MATCHING CHARACTERISTICS						
Offset Voltage		$T_A = 25^\circ\text{C}$		100	300	μV
OUTPUT CHARACTERISTICS						
Output Voltage High	V_{OH}	$R_L = 10\text{ k}\Omega$ to GND $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	14.92	14.94		V
		$R_L = 2\text{ k}\Omega$ to GND $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	14.90			V
			14.0	14.3		V
			11.0			V
Output Voltage Low	V_{OL}	$R_L = 10\text{ k}\Omega$ to GND $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		-14.96	-14.80	V
		$R_L = 2\text{ k}\Omega$ to GND $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$			-14.75	V
				-14.75	-14.60	V
					-14.0	V
Short-Circuit Limit	I_{SC}	Source/sink $f = 100\text{ kHz}$, $A_V = 1$		± 10		mA
Closed-Loop Impedance	Z_{OUT}			40		Ω
POWER SUPPLY						
Power Supply Rejection Ratio	PSRR	$V_{SY} = 3\text{ V to } 36\text{ V}$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$	100			dB
			90			dB
Supply Current per Amplifier	I_{SY}	$V_O = V_{SY}/2$ $-40^\circ\text{C} \leq T_A \leq +125^\circ\text{C}$		60	75	μA
					100	μA
DYNAMIC PERFORMANCE						
Slew Rate	SR	$R_L = 100\text{ k}\Omega$, $C_L = 30\text{ pF}$		0.4		V/ μ
Settling Time	t_S	To 0.1%, 10 V step		23.4		μs
Gain Bandwidth Product	GBP	$V_{IN} = 5\text{ mV p-p}$, $R_L = 10\text{ k}\Omega$, $A_V = 100$		786		kHz
Unity-Gain Crossover	UGC	$V_{IN} = 5\text{ mV p-p}$, $R_L = 10\text{ k}\Omega$, $A_V = 1$		800		kHz
Phase Margin	Φ_M			60		Degrees
-3 dB Closed-Loop Bandwidth	$f_{-3\text{ dB}}$	$A_V = 1$, $V_{IN} = 5\text{ mV p-p}$		1520		kHz
Channel Separation	CS	$f = 1\text{ kHz}$		100		dB
NOISE PERFORMANCE						
Voltage Noise	$e_n\text{ p-p}$	0.1 Hz to 10 Hz		0.7		$\mu\text{V p-p}$
Voltage Noise Density	e_n	$f = 1\text{ kHz}$		27		nV/ $\sqrt{\text{Hz}}$
Current Noise Density	i_n	$f = 1\text{ kHz}$		0.2		pA/ $\sqrt{\text{Hz}}$

ABSOLUTE MAXIMUM RATINGS

Table 5.

Parameter	Rating
Supply Voltage	36 V
Input Voltage	
Operating Condition	$-V \leq V_{IN} \leq +V$
Overvoltage Condition ¹	$(-V) - 32 V \leq V_{IN} \leq (+V) + 32 V$
Differential Input Voltage ²	$\pm V_{SY}$
Input Current	± 5 mA
Output Short-Circuit Duration to GND	Indefinite
Storage Temperature Range	-65°C to $+150^{\circ}\text{C}$
Operating Temperature Range	-40°C to $+125^{\circ}\text{C}$
Junction Temperature Range	-65°C to $+150^{\circ}\text{C}$
Lead Temperature (Soldering, 60 seconds)	300°C

¹ Performance not guaranteed during overvoltage conditions.

² Limit the input current to ± 5 mA.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

THERMAL RESISTANCE

θ_{JA} is specified for the device soldered on a 4-layer JEDEC standard printed circuit board (PCB) with zero airflow. The exposed pad is soldered to the application board.

Table 6. Thermal Resistance

Package Type	θ_{JA}	θ_{JC}	Unit
8-Lead MSOP (RM-8)	142	45	$^{\circ}\text{C}/\text{W}$
8-Lead LFCSP (CP-8-10)	76	43	$^{\circ}\text{C}/\text{W}$
14-Lead TSSOP (RU-14)	112	35	$^{\circ}\text{C}/\text{W}$
16-Lead LFCSP (CP-16-22)	75	12	$^{\circ}\text{C}/\text{W}$

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS



Figure 4. 8-Lead, MSOP (RM-8), ADA4096-2

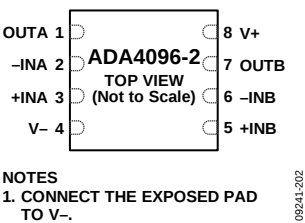


Figure 5. 8-Lead LFCSP (CP-8-10), ADA4096-2

Table 7. Pin Function Descriptions, ADA4096-2

Pin No. ¹		Mnemonic	Description
8-Lead MSOP	8-Lead LFCSP		
1	1	OUTA	Output Channel A.
2	2	–INA	Negative Input Channel A.
3	3	+INA	Positive Input Channel A.
4	4	V–	Negative Supply Voltage.
5	5	+INB	Positive Input Channel B.
6	6	–INB	Negative Input Channel B.
7	7	OUTB	Output Channel B.
8	8	V+	Positive Supply Voltage.
N/A	EP ²	EPAD	Exposed Pad. ² For the ADA4096-2 (8-lead LFCSP only), connect the exposed pad to V–.

¹ N/A means not applicable.
² The exposed pad is not shown in the pin configuration diagram.

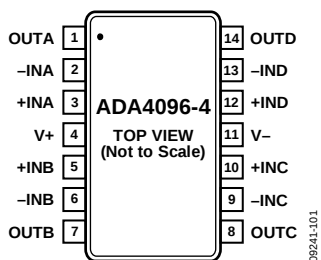
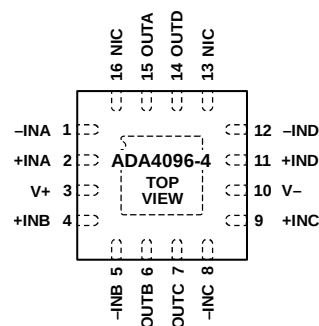


Figure 6. 14-Lead TSSOP (RU-14), ADA4096-4



NOTES
 1. NIC = NOT INTERNALLY CONNECTED.
 2. CONNECT THE EXPOSED PAD TO V-.

Figure 7. 16-Lead LFCSP (CP-16-22), ADA4096-4

Table 8. Pin Function Descriptions, ADA4096-4

Pin No. ¹		Mnemonic	Description
14-Lead TSSOP	16-Lead LFCSP		
1	15	OUTA	Output Channel A.
2	1	-INA	Negative Input Channel A.
3	2	+INA	Positive Input Channel A.
4	3	V+	Positive Supply Voltage.
5	4	+INB	Positive Input Channel B.
6	5	-INB	Negative Input Channel B.
7	6	OUTB	Output Channel B.
8	7	OUTC	Output Channel C.
9	8	-INC	Negative Input Channel C.
10	9	+INC	Positive Input Channel C.
11	10	V-	Negative Supply Voltage.
12	11	+IND	Positive Input Channel D.
13	12	-IND	Negative Input Channel D.
14	14	OUTD	Output Channel D.
N/A	13	NIC	No Internal Connection.
N/A	16	NIC	No Internal Connection.
N/A	EP ²	EPAD	Exposed Pad. ² For the ADA4096-4 (16-lead LFCSP only), connect the exposed pad to V-.

¹ N/A means not applicable.² The exposed pad is not shown in the pin configuration diagram.

TYPICAL PERFORMANCE CHARACTERISTICS

$T_A = 25^\circ\text{C}$, unless otherwise noted. All typical performance characteristics shown are for the ADA4096-2 only.

$\pm 1.5\text{ V}$ CHARACTERISTICS

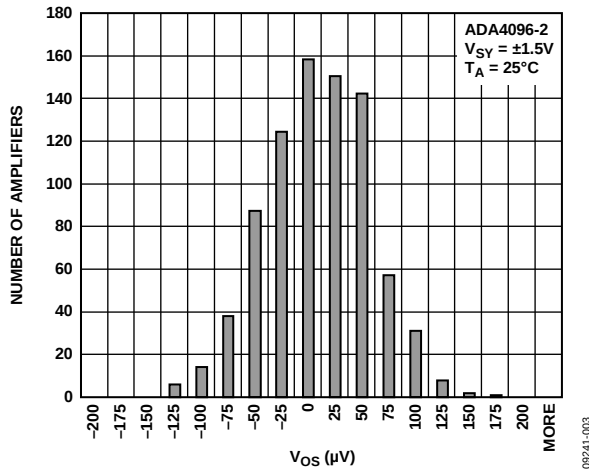


Figure 8. Input Offset Voltage (V_{OS}) Distribution

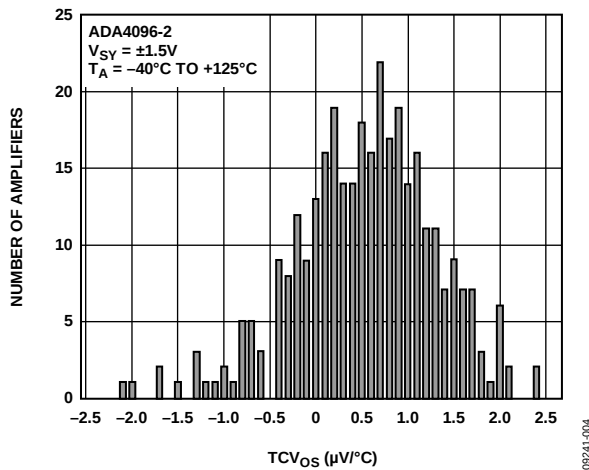


Figure 9. Offset Voltage Drift (TCV_{OS}) Distribution

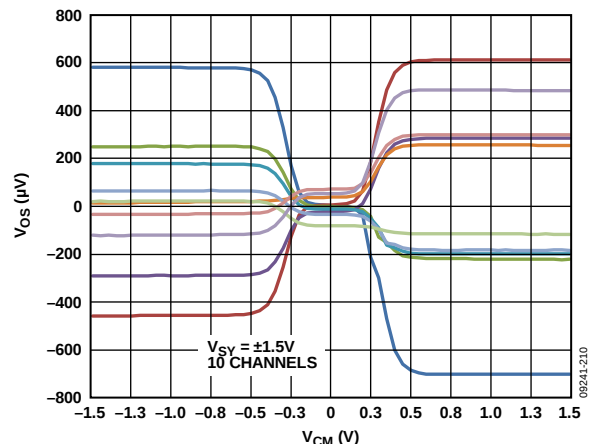


Figure 10. Input Offset Voltage (V_{OS}) vs. Common-Mode Voltage (V_{CM})

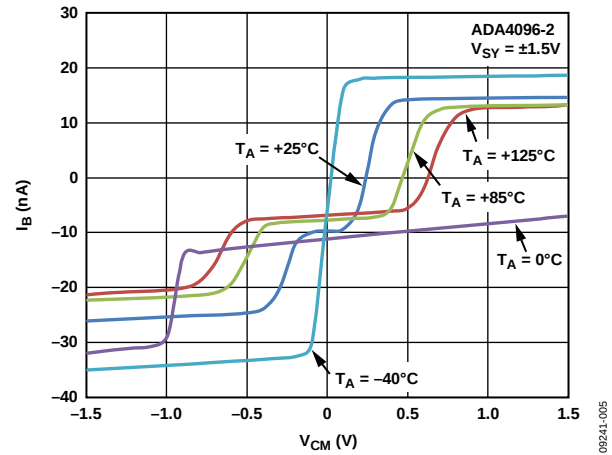


Figure 11. Input Bias Current (I_B) vs. V_{CM} for Various Temperatures

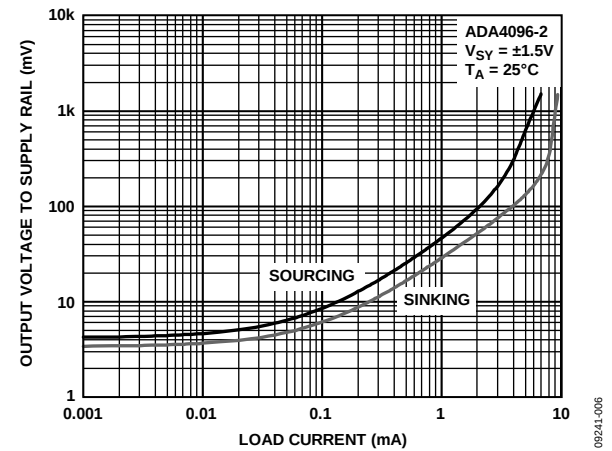


Figure 12. Output Voltage to Supply Rail vs. Load Current

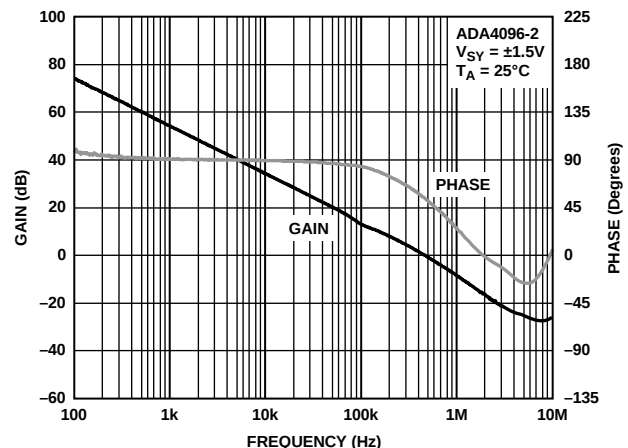


Figure 13. Open-Loop Gain and Phase vs. Frequency

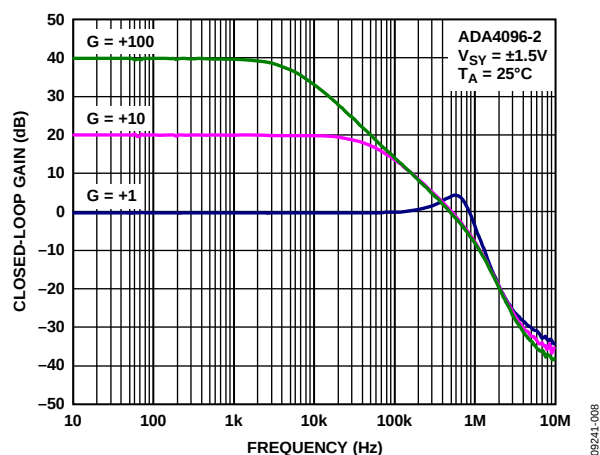


Figure 14. Closed-Loop Gain vs. Frequency

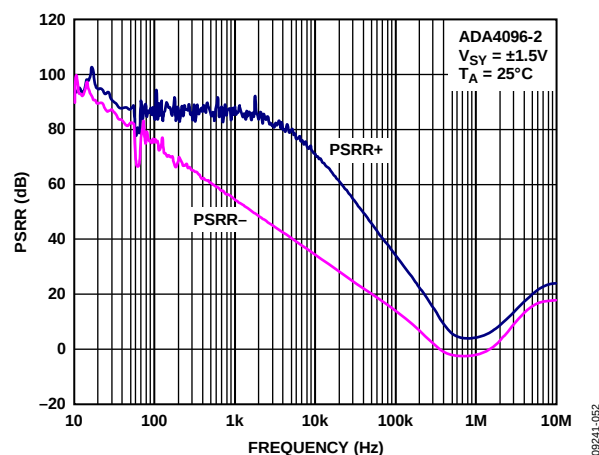


Figure 16. PSRR vs. Frequency

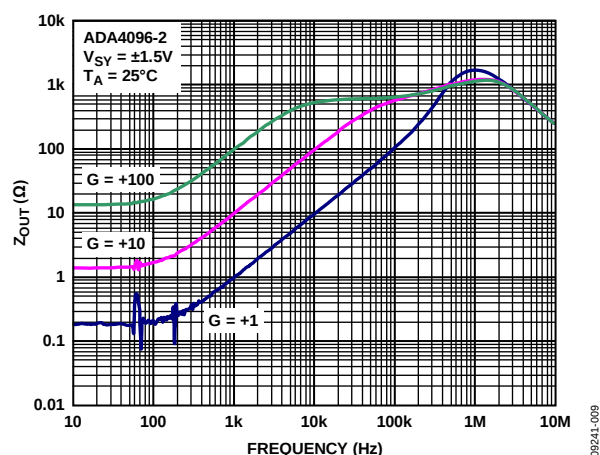
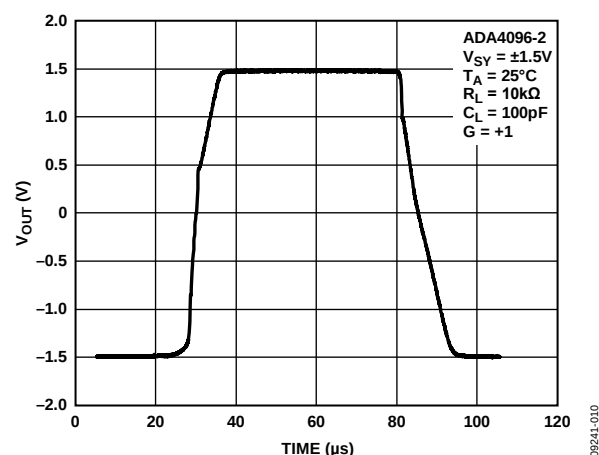
Figure 15. Output Impedance (Z_{OUT}) vs. Frequency

Figure 17. Large Signal Transient Response

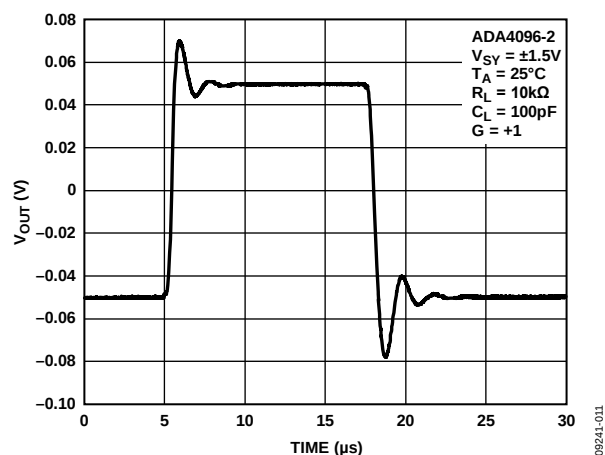


Figure 18. Small Signal Transient Response

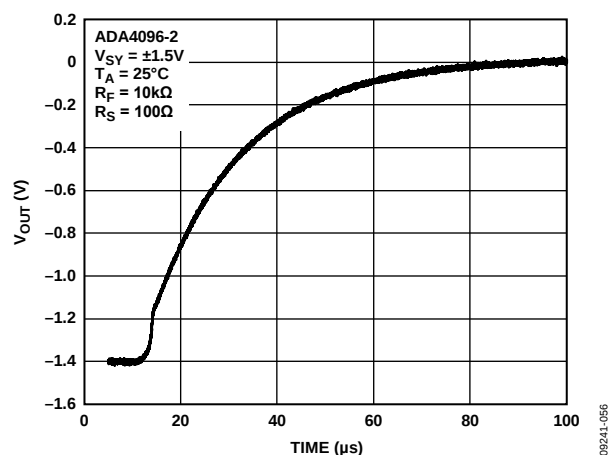


Figure 20. Negative Overload Recovery

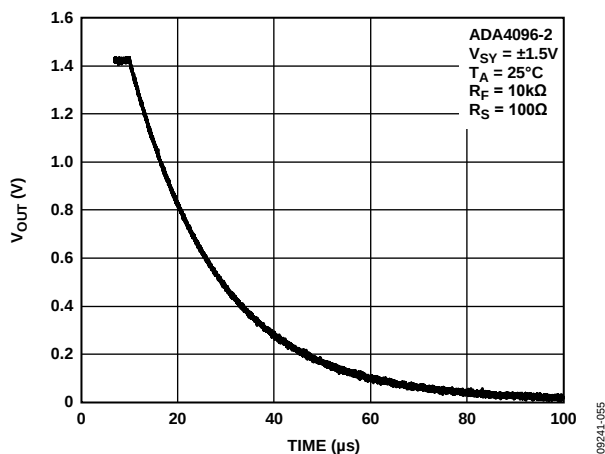


Figure 19. Positive Overload Recovery

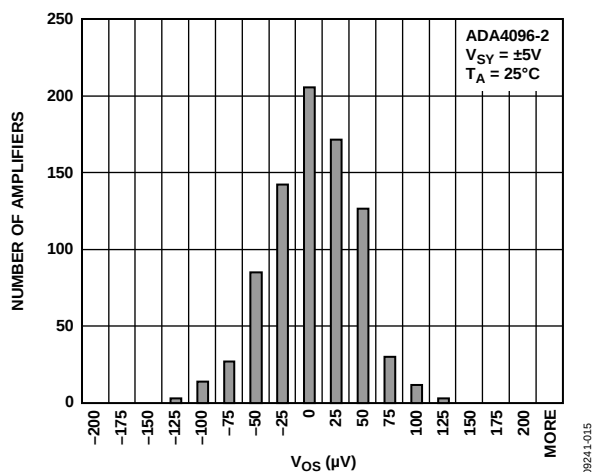
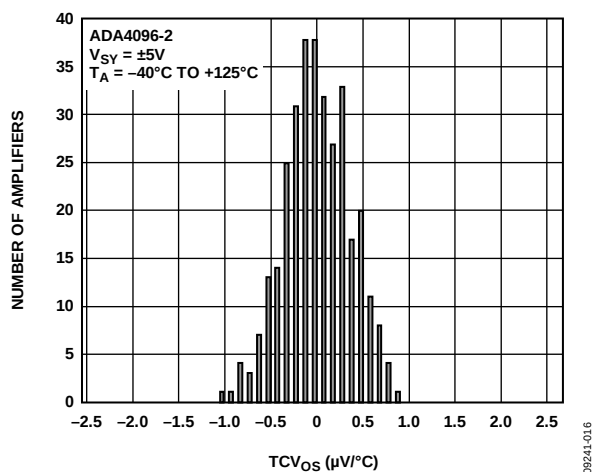
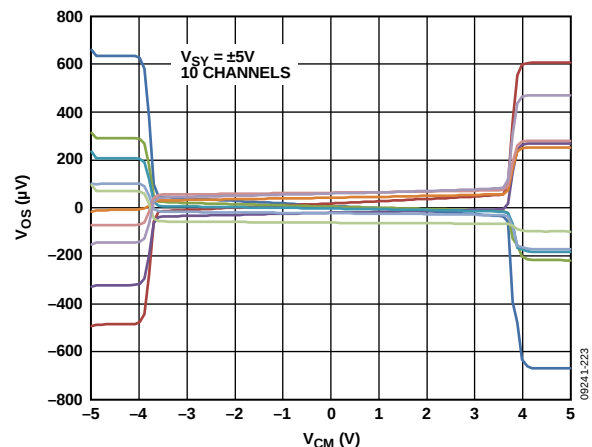
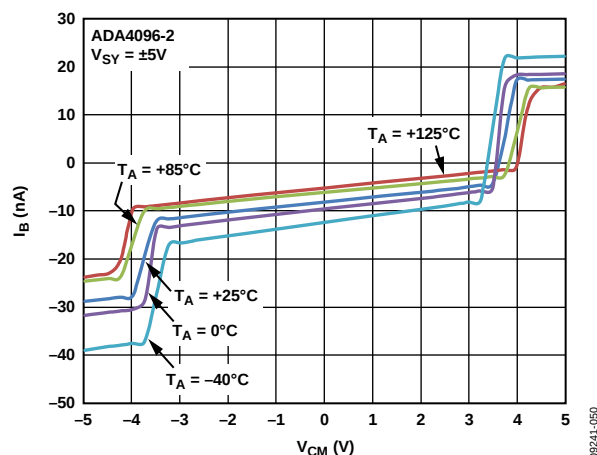
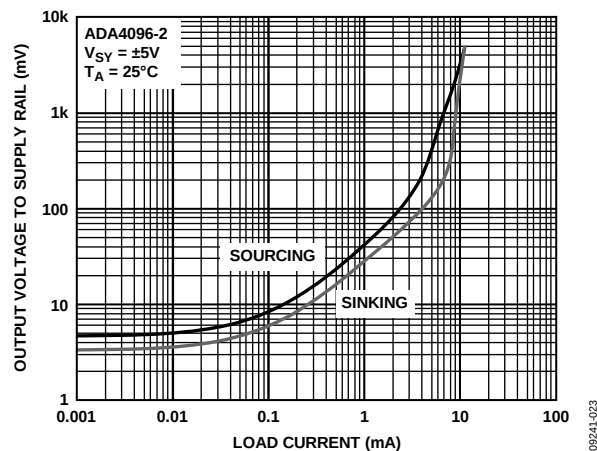
±5 V CHARACTERISTICSFigure 21. Input Offset Voltage (V_{OS}) DistributionFigure 22. Offset Voltage Drift (TCV_{OS}) DistributionFigure 23. Input Offset Voltage (V_{OS}) vs. Common-Mode Voltage (V_{CM})Figure 24. Input Bias Current (I_B) vs. V_{CM} for Various Temperatures

Figure 25. Output Voltage to Supply Rail vs. Load Current

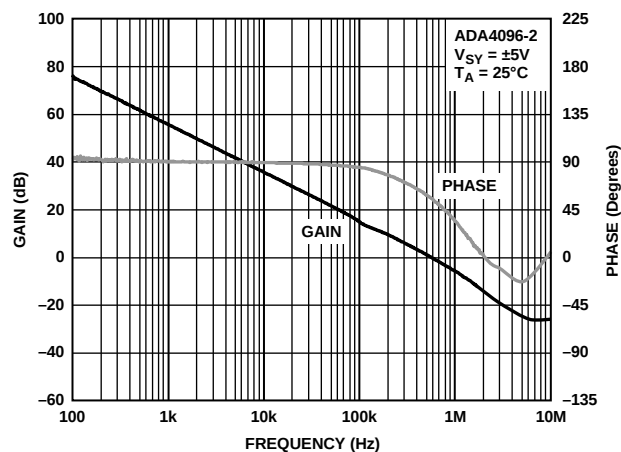


Figure 26. Open-Loop Gain and Phase vs. Frequency

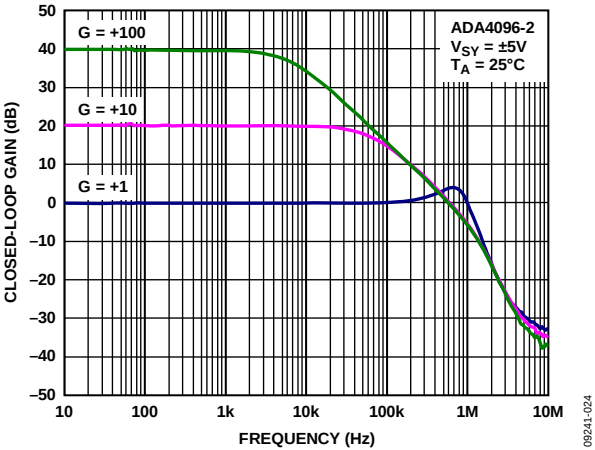


Figure 27. Closed-Loop Gain vs. Frequency

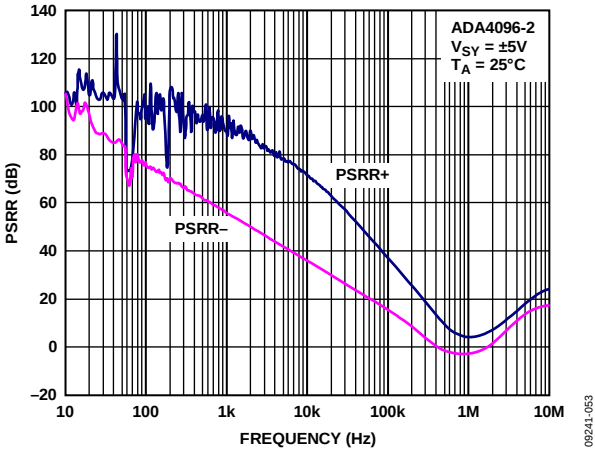


Figure 29. PSRR vs. Frequency

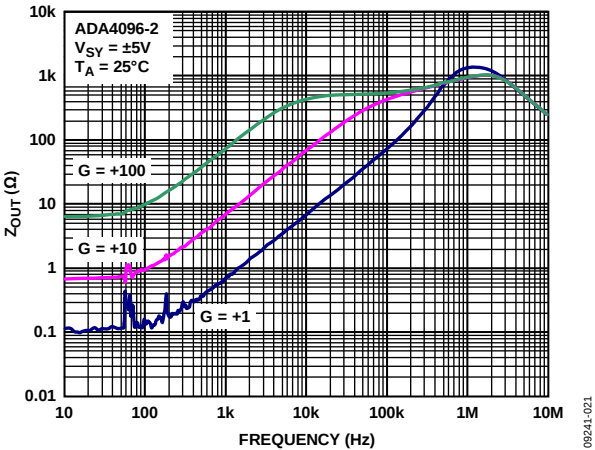


Figure 28. Output Impedance (Z_{OUT}) vs. Frequency.

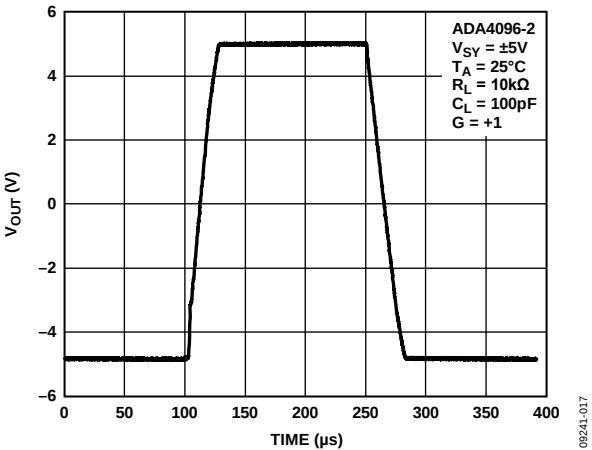


Figure 30. Large Signal Transient Response

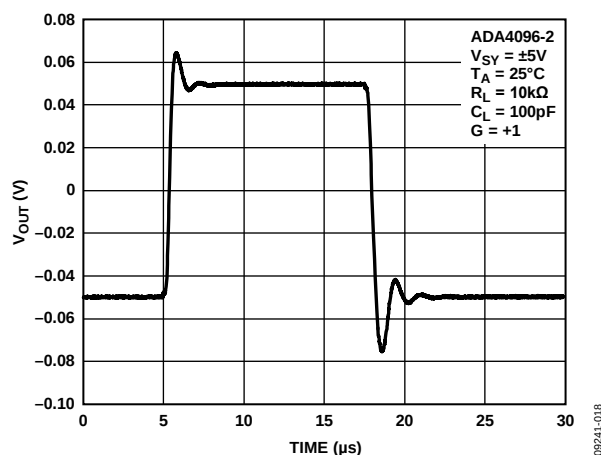


Figure 31. Small Signal Transient Response

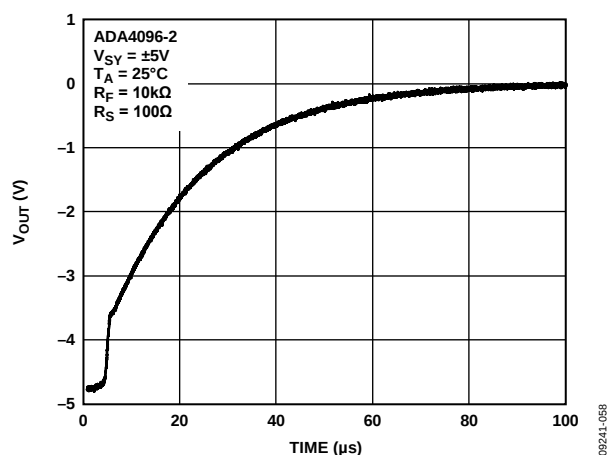


Figure 33. Negative Overload Recovery

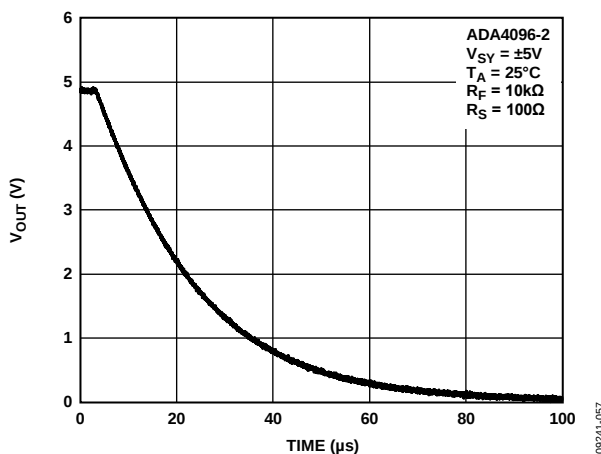


Figure 32. Positive Overload Recovery

±15 V CHARACTERISTICS

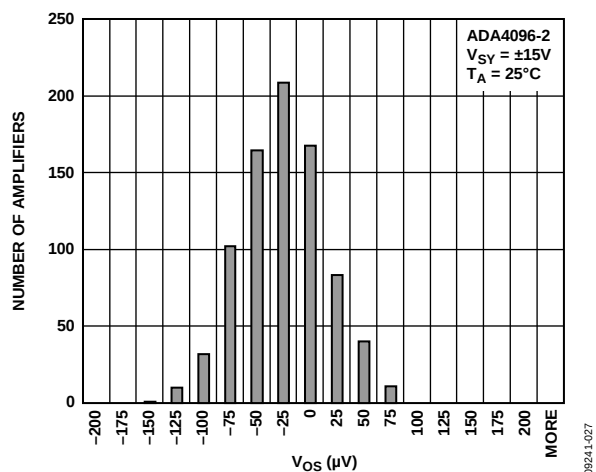


Figure 34. Input Offset Voltage (V_{OS}) Distribution

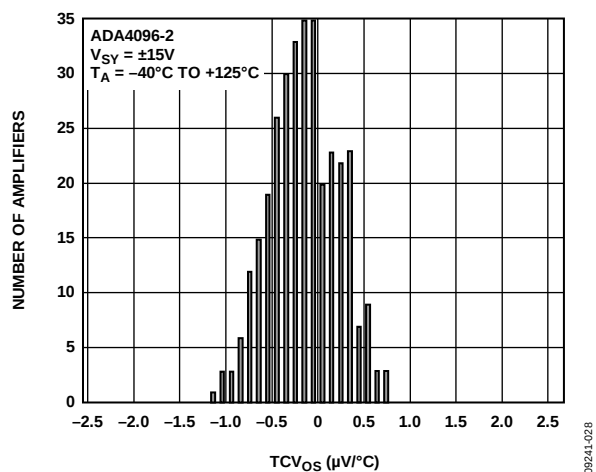


Figure 35. Offset Voltage Drift (TCV_{OS}) Distribution

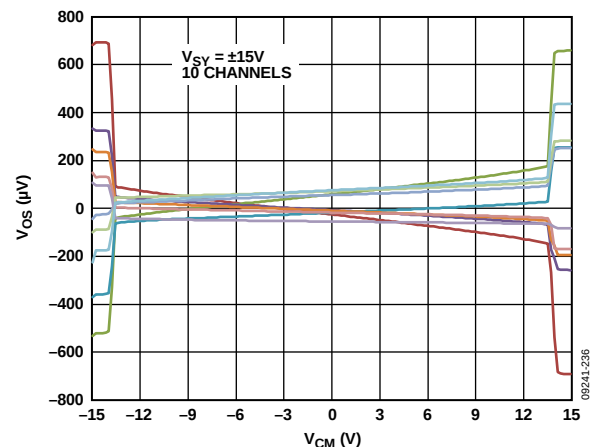


Figure 36. Input Offset Voltage (V_{OS}) vs. Common-Mode Voltage (V_{CM})

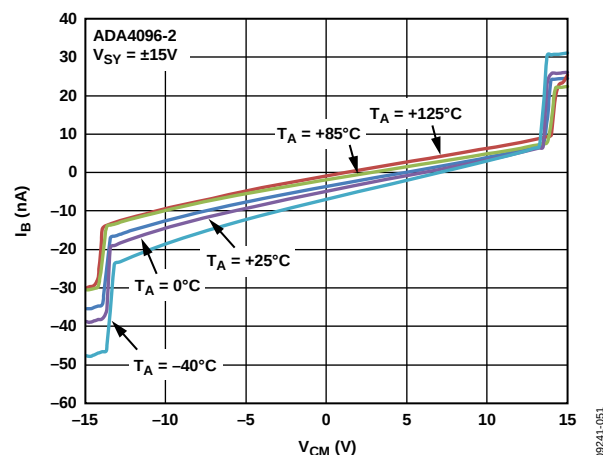


Figure 37. Input Bias Current (I_B) vs. V_{CM} for Various Temperatures

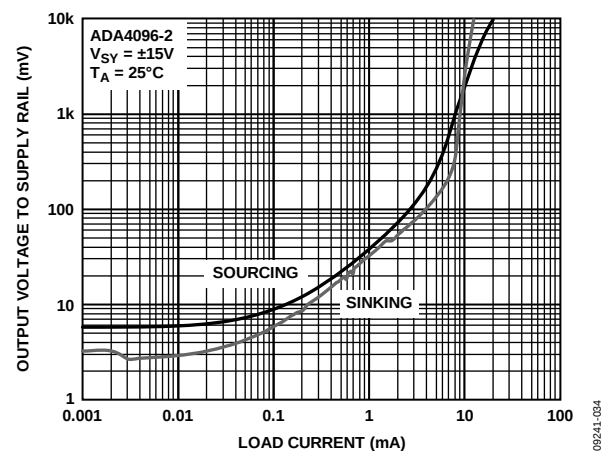


Figure 38. Output Voltage to Supply Rail vs. Load Current

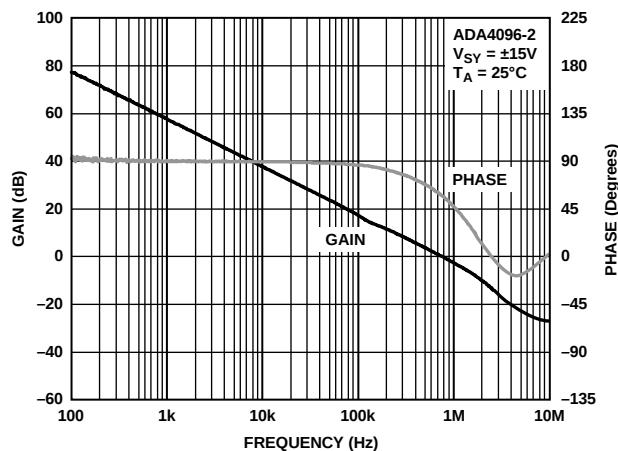


Figure 39. Open-Loop Gain and Phase vs. Frequency

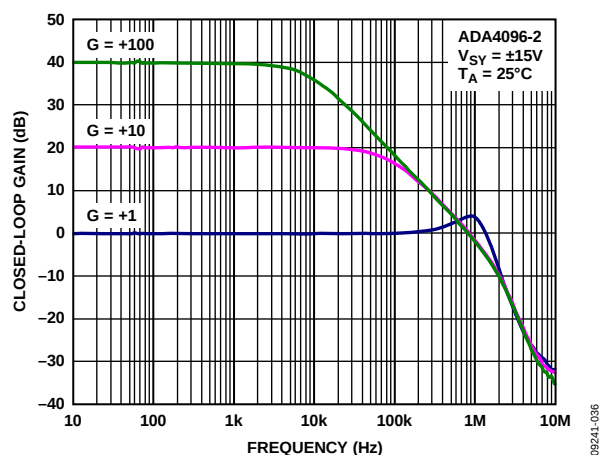


Figure 40. Closed-Loop Gain vs. Frequency

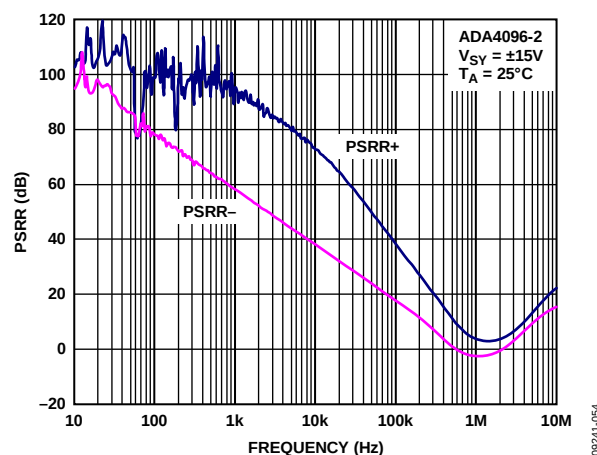


Figure 42. PSRR vs. Frequency

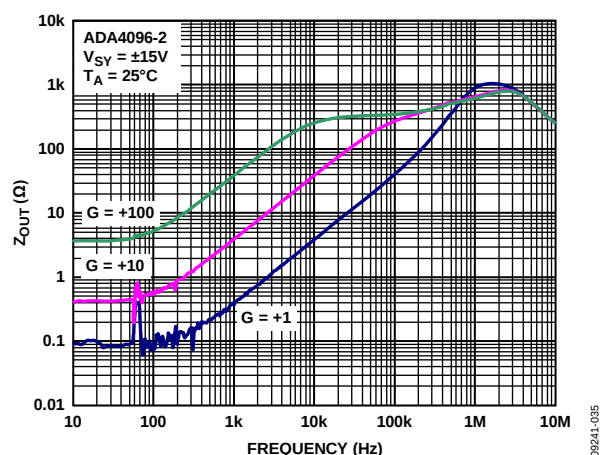
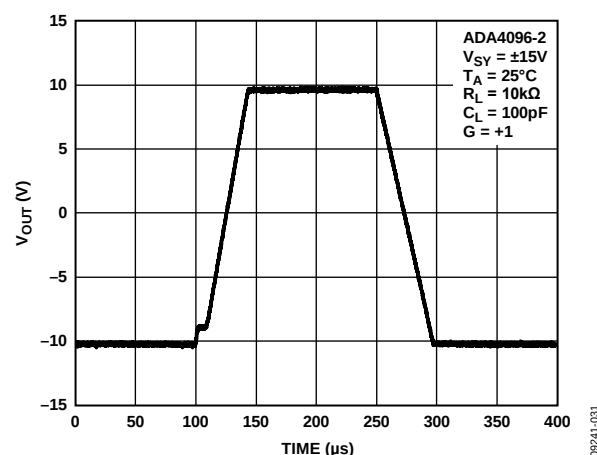
Figure 41. Output Impedance (Z_{OUT}) vs. Frequency

Figure 43. Large Signal Transient Response

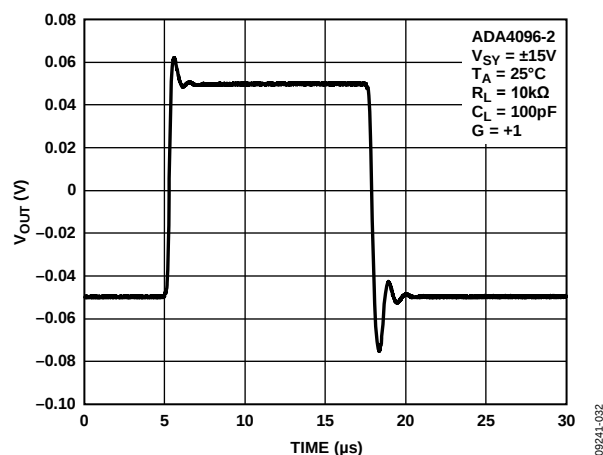


Figure 44. Small Signal Transient Response

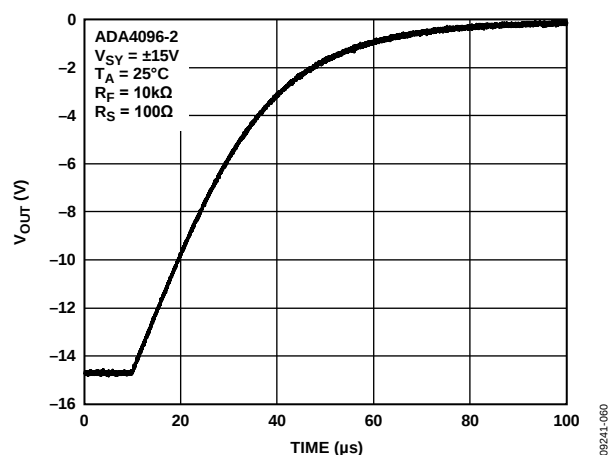


Figure 46. Negative Overload Recovery

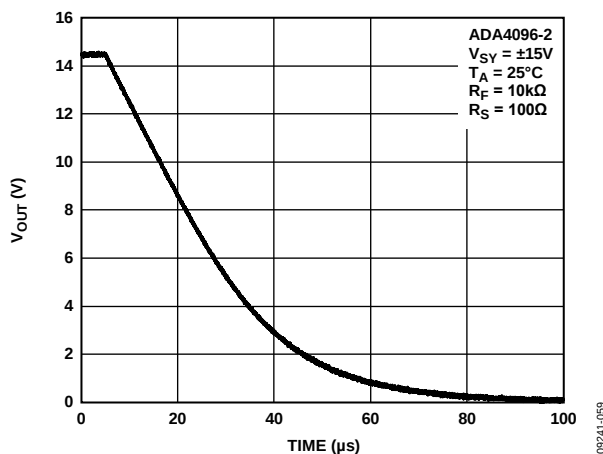


Figure 45. Positive Overload Recovery

COMPARATIVE VOLTAGE AND VARIABLE VOLTAGE GRAPHS

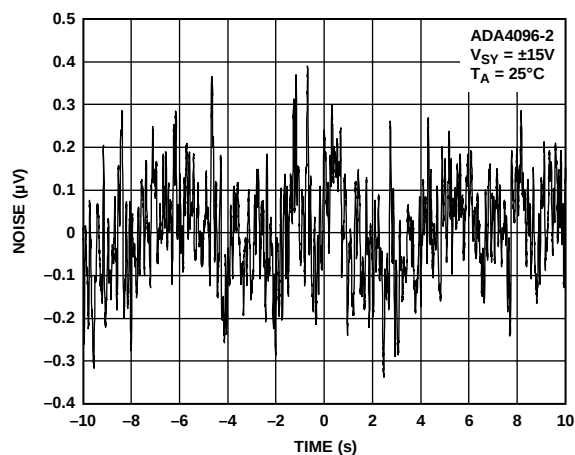


Figure 47. Input Voltage Noise, 0.1 Hz to 10 Hz Bandwidth

09241-039

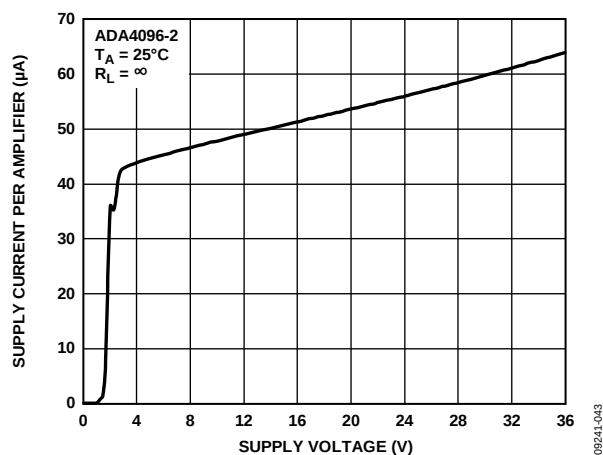


Figure 50. Supply Current per Amplifier vs. Supply Voltage

09241-043

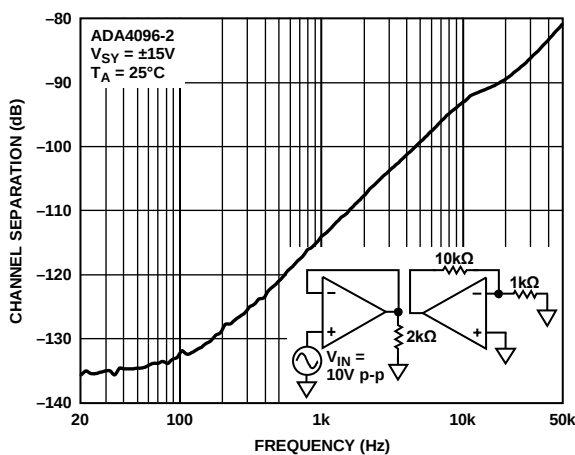
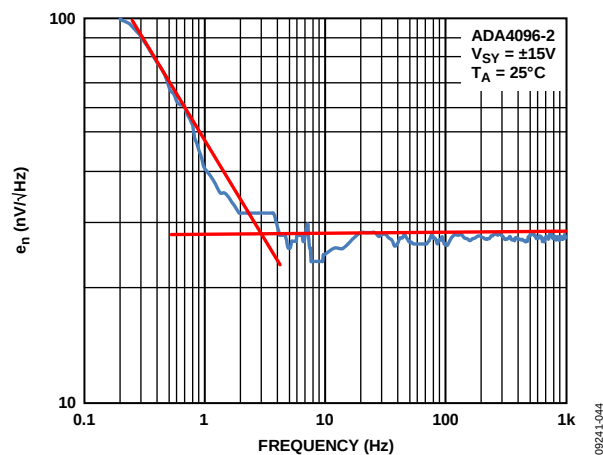


Figure 48. Channel Separation vs. Frequency

09241-040

Figure 51. Voltage Noise Density (e_n) vs. Frequency

09241-044

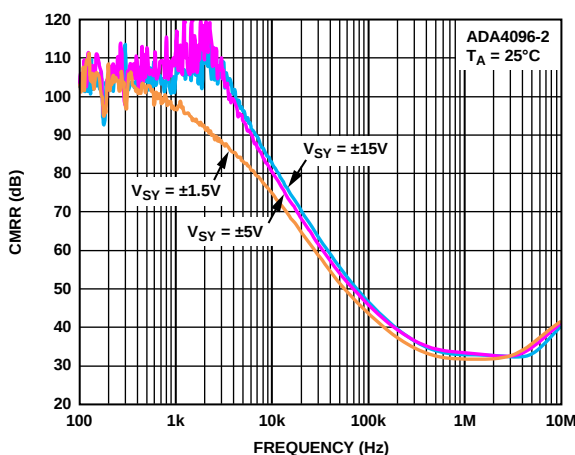
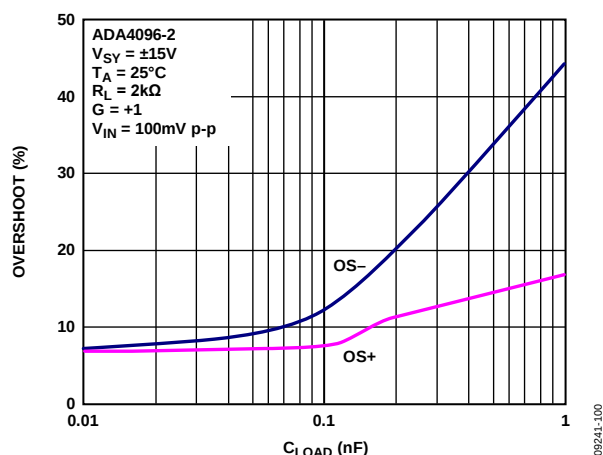


Figure 49. CMRR vs. Frequency

09241-041

Figure 52. Overshoot vs. Load Capacitance (C_{LOAD})

09241-100

THEORY OF OPERATION

INPUT STAGE

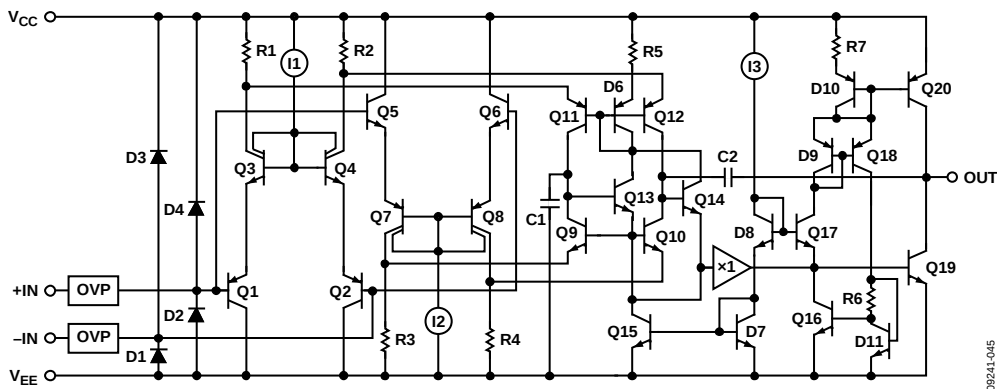


Figure 53. Simplified Schematic, ADA4096-2

Figure 53 shows a simplified schematic of the ADA4096-2. The input stage comprises two differential pairs (Q1 to Q4 and Q5 to Q8) operating in parallel. When the input common-mode voltage approaches $V_{CC} - 1.5\text{ V}$, Q1 to Q4 shut down as I1 reaches its minimum voltage compliance. Conversely, when the input common-mode voltage approaches $V_{EE} + 1.5\text{ V}$, Q5 to Q8 shut down as I2 reaches its minimum voltage compliance. This topology allows for maximum input dynamic range because the amplifier can function with its inputs at 200 mV outside the rail (at room temperature).

As with any rail-to-rail input amplifier, V_{OS} mismatch between the two input pairs determines the CMRR of the amplifier. If the input common-mode voltage range is kept within 1.5 V of each rail, transitions between the input pairs are avoided, thus improving the CMRR by approximately 10 dB (see Table 3 and Table 4).

PHASE INVERSION

Some single-supply amplifiers exhibit phase inversion when the input signal extends beyond the common-mode voltage range of the amplifier. When the input devices become saturated, the inverting and noninverting inputs exchange functions, causing the output to move in the opposing direction.

Although phase inversion persists for only as long as the inputs are saturated, it can be detrimental to applications where the amplifier is part of a closed-loop system. The ADA4096-2 family is free from phase inversion over the entire common-mode voltage range, as well as the overvoltage protected range that is stated in the Absolute Maximum Ratings section, Table 5. Figure 54 shows the ADA4096-2 in a unity-gain configuration with the input signal at $\pm 40\text{ V}$ and the amplifier supplies at $\pm 10\text{ V}$.

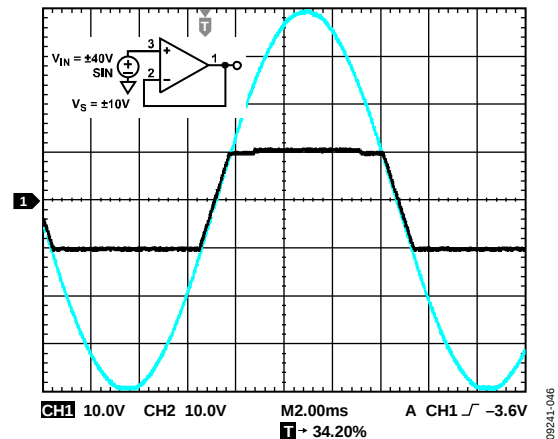


Figure 54. No Phase Reversal

INPUT OVERVOLTAGE PROTECTION

The ADA4096-2 family inputs are protected from input voltage excursions up to 32 V outside each rail. This feature is of particular importance in applications with power supply sequencing issues that could cause the signal source to be active before the power supplies.

Figure 55 shows the input current limiting capability of the ADA4096-2 (green curves) compared to using a 5 k Ω series resistor (red curves).

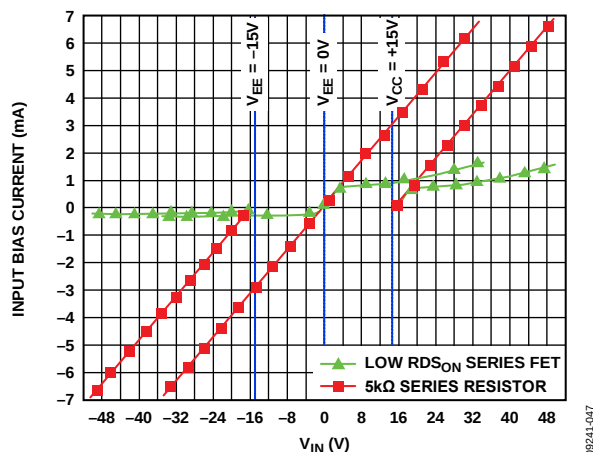


Figure 55. Input Current Limiting Capability

Figure 55 was generated with the ADA4096-2 in a buffer configuration with the supplies connected to GND (or ± 15 V) and the positive input swept until it exceeds the supplies by 32 V. In general, input current is limited to 1 mA during positive overvoltage conditions and 200 μ A during negative undervoltage conditions. For example, at an overvoltage of 20 V, the ADA4096-2 input current is limited to 1 mA, providing a current-limit equivalent to a series 20 k Ω resistor. Figure 55 also shows that the current limiting circuitry is active whether the amplifier is powered or not.

Note that Figure 55 represents input protection under abnormal conditions only. The correct amplifier operation input voltage range (IVR) is specified in Table 2 to Table 4.

COMPARATOR OPERATION

Although op amps are quite different from comparators, occasionally an unused section of a dual or a quad op amp may be pressed into service as a comparator; however, this is not recommended for any rail-to-rail output op amps. For rail-to-rail output op amps, the output stage is generally a ratioed current mirror with bipolar or metal-oxide semiconductor field-effect (MOSFET) transistors. With the device operating in open loop, the second stage increases the current drive to the ratioed mirror to close the loop, but it cannot, which results in an increase in supply current. With the op amp configured as a comparator, the supply current can be significantly higher (see Figure 56).

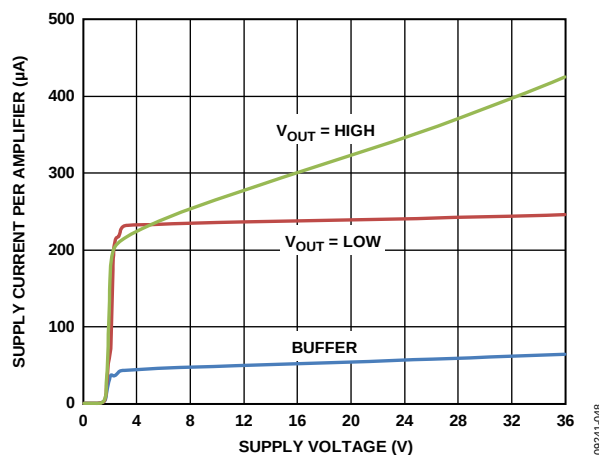


Figure 56. Comparator Supply Current

OUTLINE DIMENSIONS

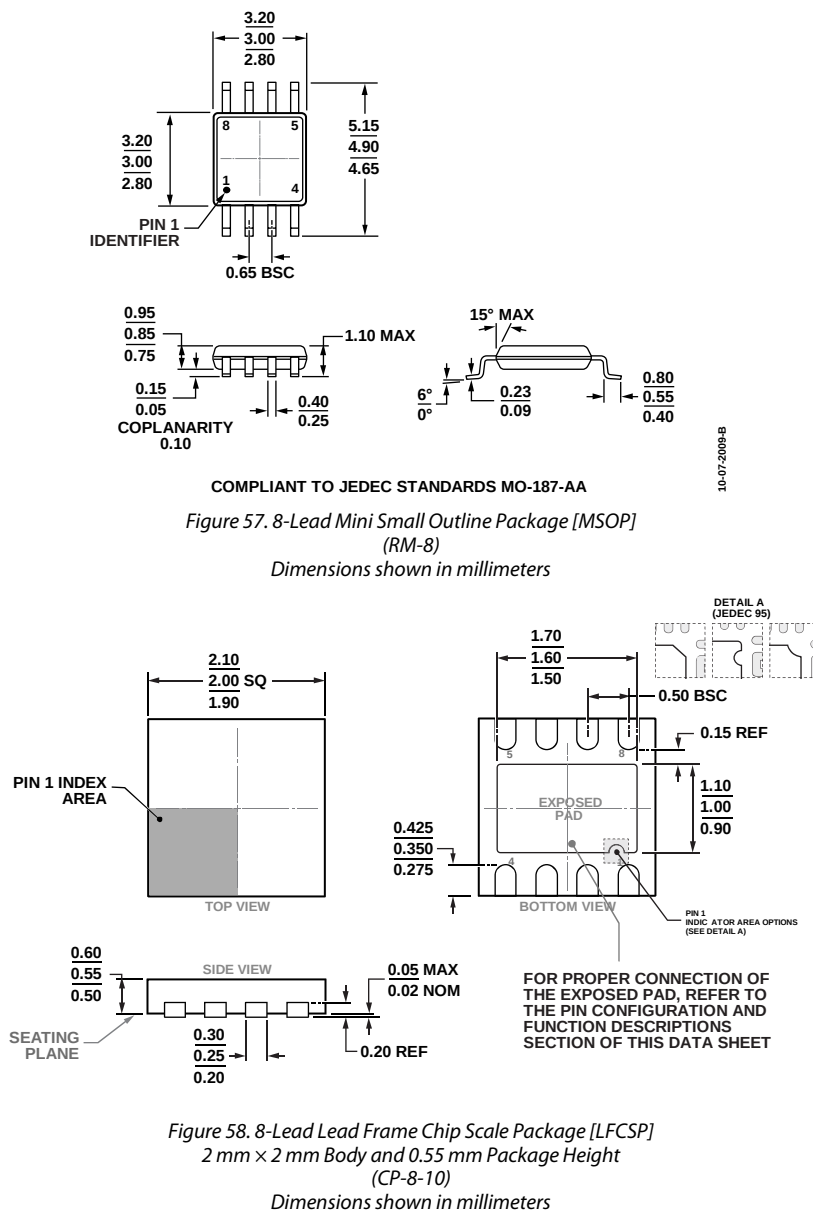
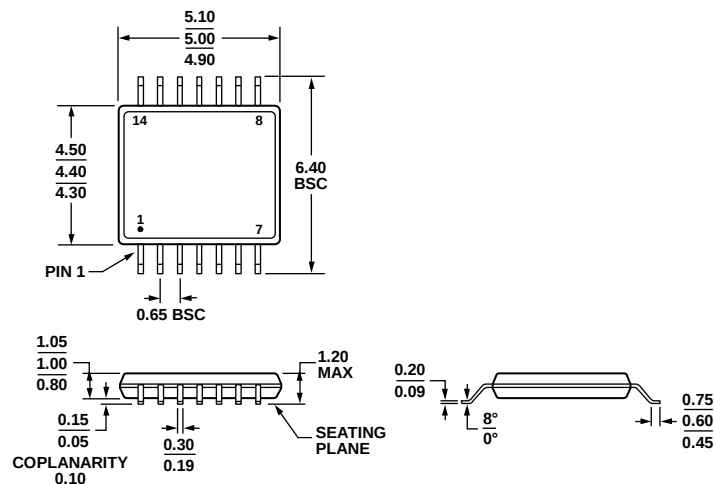


Figure 58. 8-Lead Lead Frame Chip Scale Package [LFCSP]
2 mm × 2 mm Body and 0.55 mm Package Height
(CP-8-10)

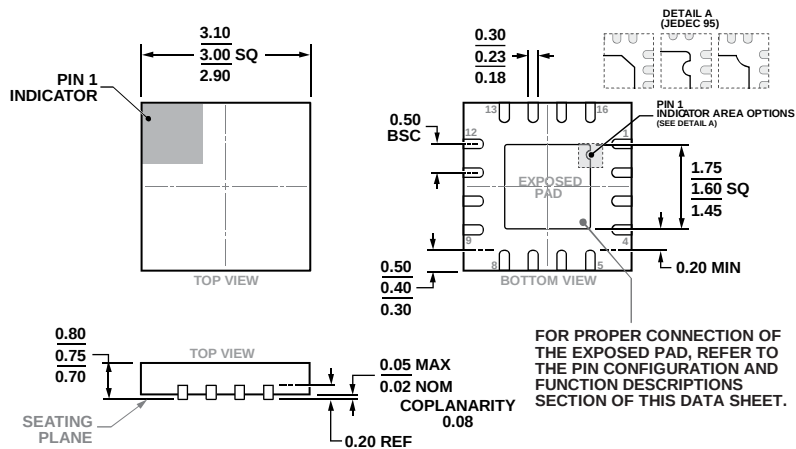
Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-153-AB-1

Figure 59. 14-Lead Thin Shrink Small Outline Package [TSSOP]
(RU-14)

Dimensions shown in millimeters



COMPLIANT TO JEDEC STANDARDS MO-220-WEED-6.

Figure 60. 16-Lead Lead Frame Chip Scale Package [LFCSP]
3 mm x 3 mm Body and 0.75 mm Package Height
(CP-16-22)

Dimensions shown in millimeters

ORDERING GUIDE

Model ^{1, 2}	Temperature Range	Package Description	Package Option	Branding
ADA4096-2ARMZ	−40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	A2T
ADA4096-2ARMZ-R7	−40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	A2T
ADA4096-2ARMZ-RL	−40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	A2T
ADA4096-2ACPZ-R7	−40°C to +125°C	8-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-8-10	A4
ADA4096-2ACPZ-RL	−40°C to +125°C	8-Lead Lead Frame Chip Scale Package [LFCSP_UD]	CP-8-10	A4
ADA4096-2WARMZ-R7	−40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	A2T
ADA4096-2WARMZ-RL	−40°C to +125°C	8-Lead Mini Small Outline Package [MSOP]	RM-8	A2T
ADA4096-4ARUZ	−40°C to +125°C	14-Lead Thin Shrink Small Outline Package [TSSOP]	RU-14	A30
ADA4096-4ARUZ-R7	−40°C to +125°C	14-Lead Thin Shrink Small Outline Package [TSSOP]	RU-14	
ADA4096-4ARUZ-RL	−40°C to +125°C	14-Lead Thin Shrink Small Outline Package [TSSOP]	RU-14	
ADA4096-4ACPZ-R7	−40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP_WQ]	CP-16-22	
ADA4096-4ACPZ-RL	−40°C to +125°C	16-Lead Lead Frame Chip Scale Package [LFCSP_WQ]	CP-16-22	

¹ Z = RoHS Compliant Part.² W = Qualified for Automotive Applications.

AUTOMOTIVE PRODUCTS

The [ADA4096-2W](#) models are available with controlled manufacturing to support the quality and reliability requirements of automotive applications. Note that these automotive models may have specifications that differ from the commercial models; therefore, designers should review the Specifications section of this data sheet carefully. Only the automotive grade products shown are available for use in automotive applications. Contact your local Analog Devices account representative for specific product ordering information and to obtain the specific Automotive Reliability reports for these models.

NOTES